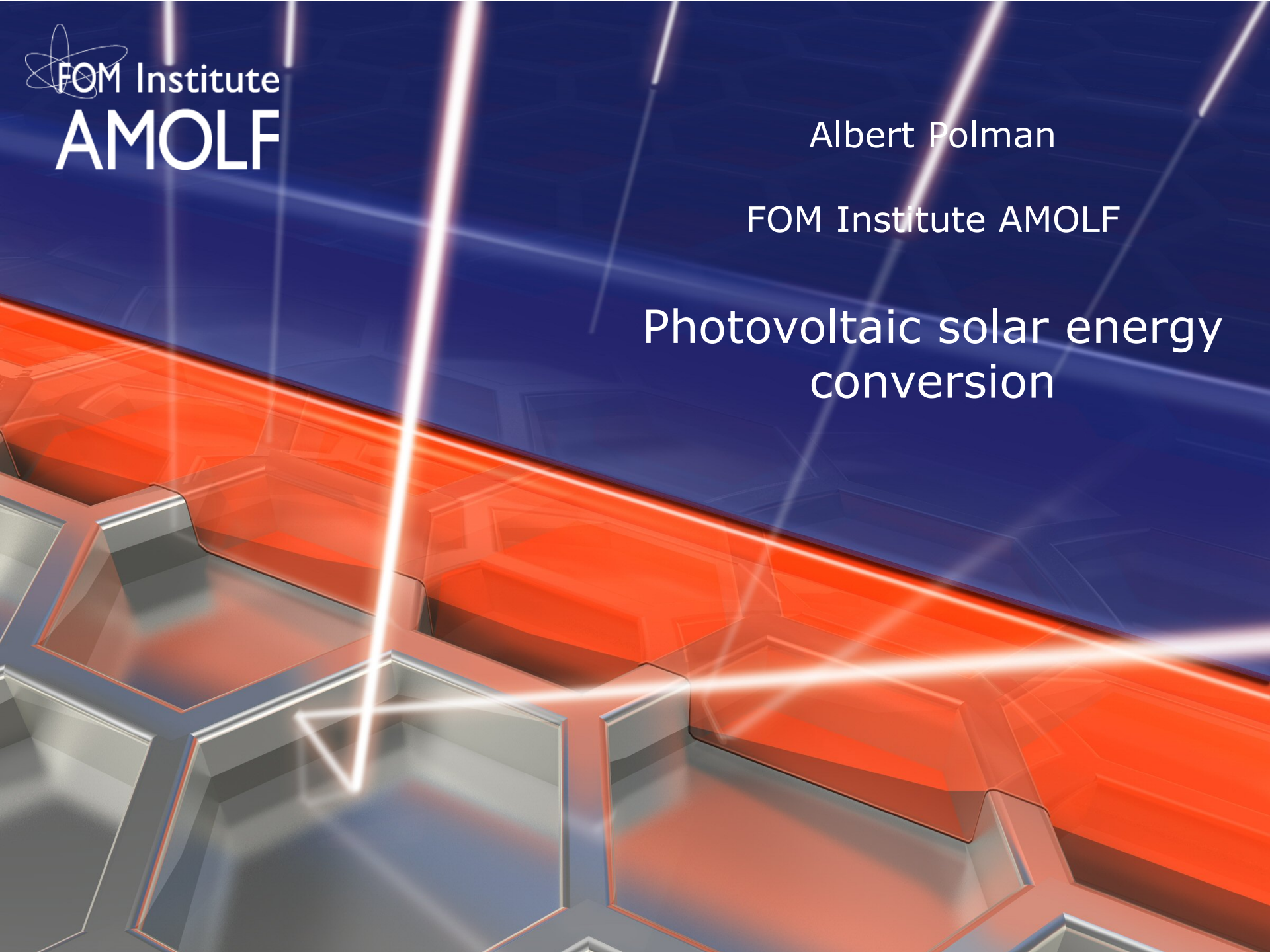


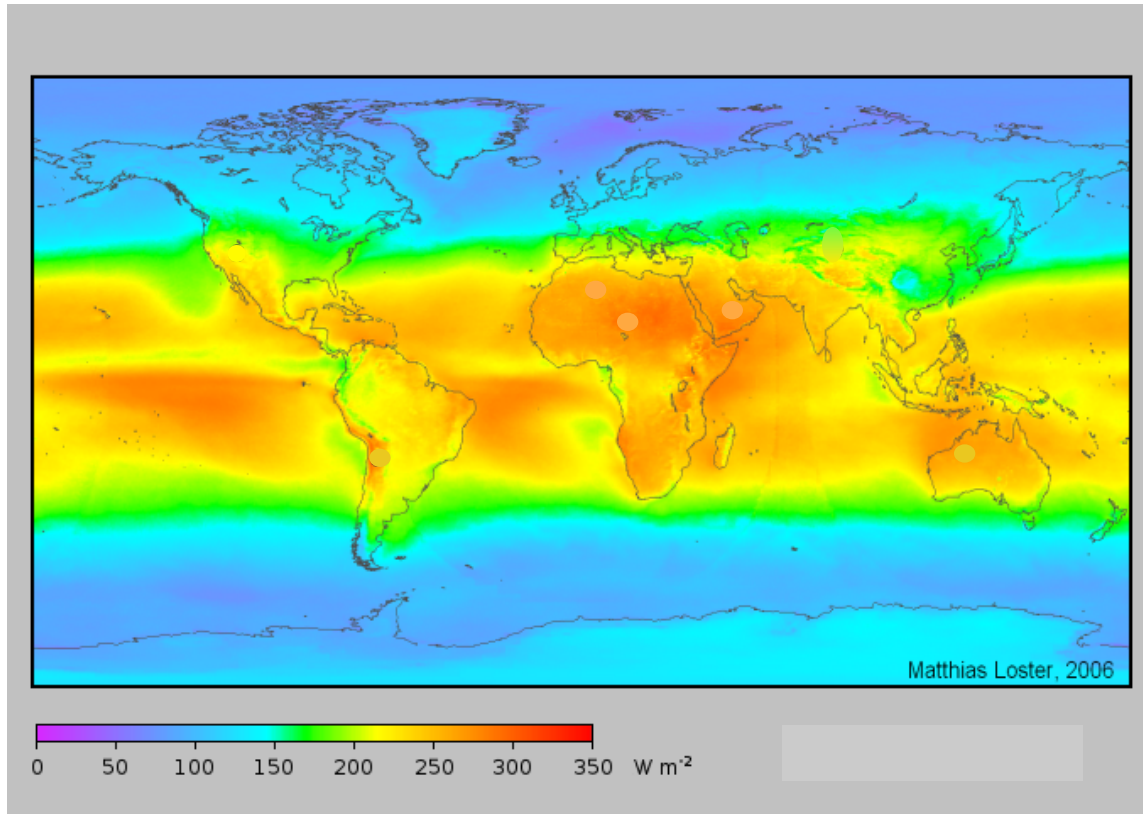
Albert Polman

FOM Institute AMOLF

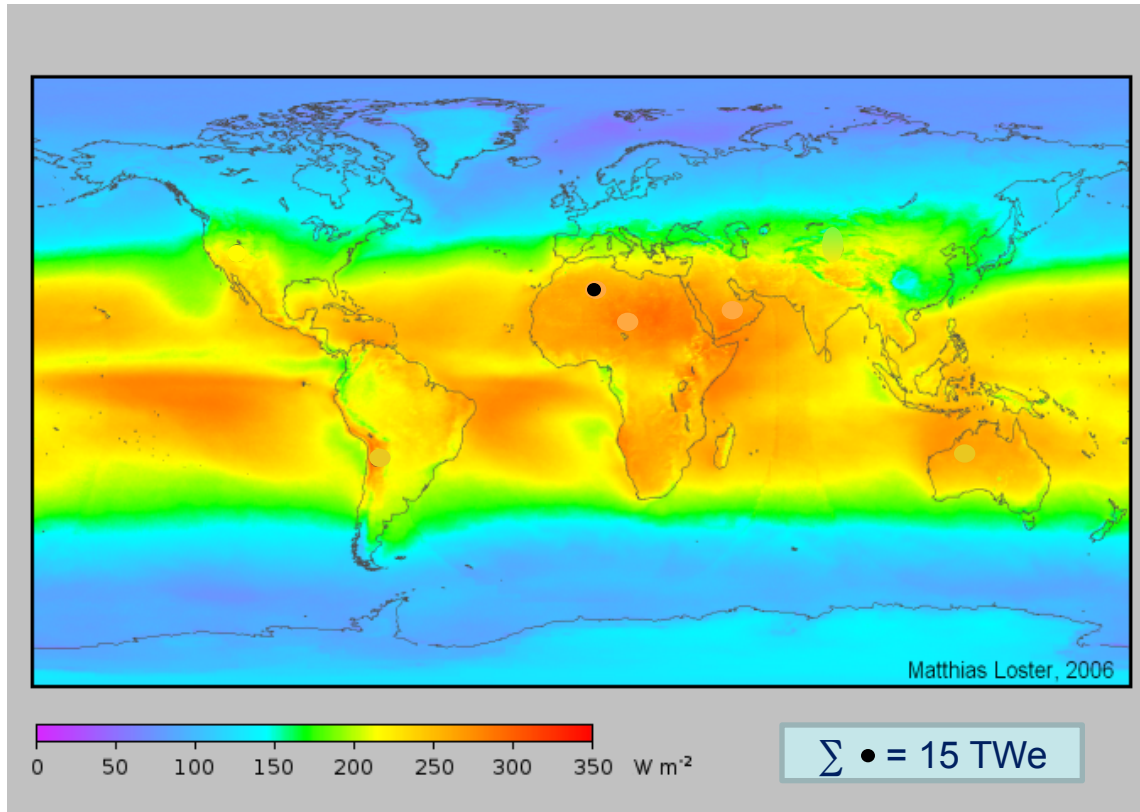
Photovoltaic solar energy conversion



Solar irradiance on earth



Solar irradiance on earth



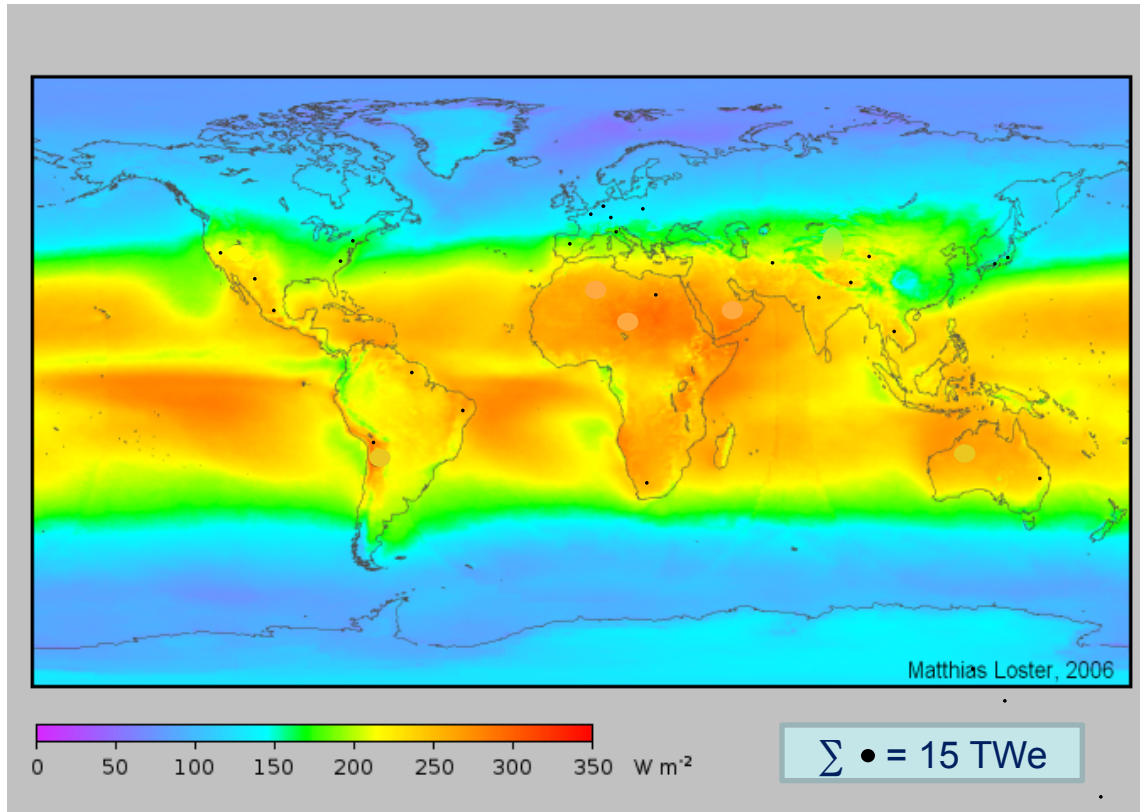
Black dot:

area of solar
panels needed
to generate all
of the worlds
primary energy

(all energy consumed:
electricity, heat, fossil
fuels)

assuming 30 %
efficient solar panels

Solar irradiance on earth



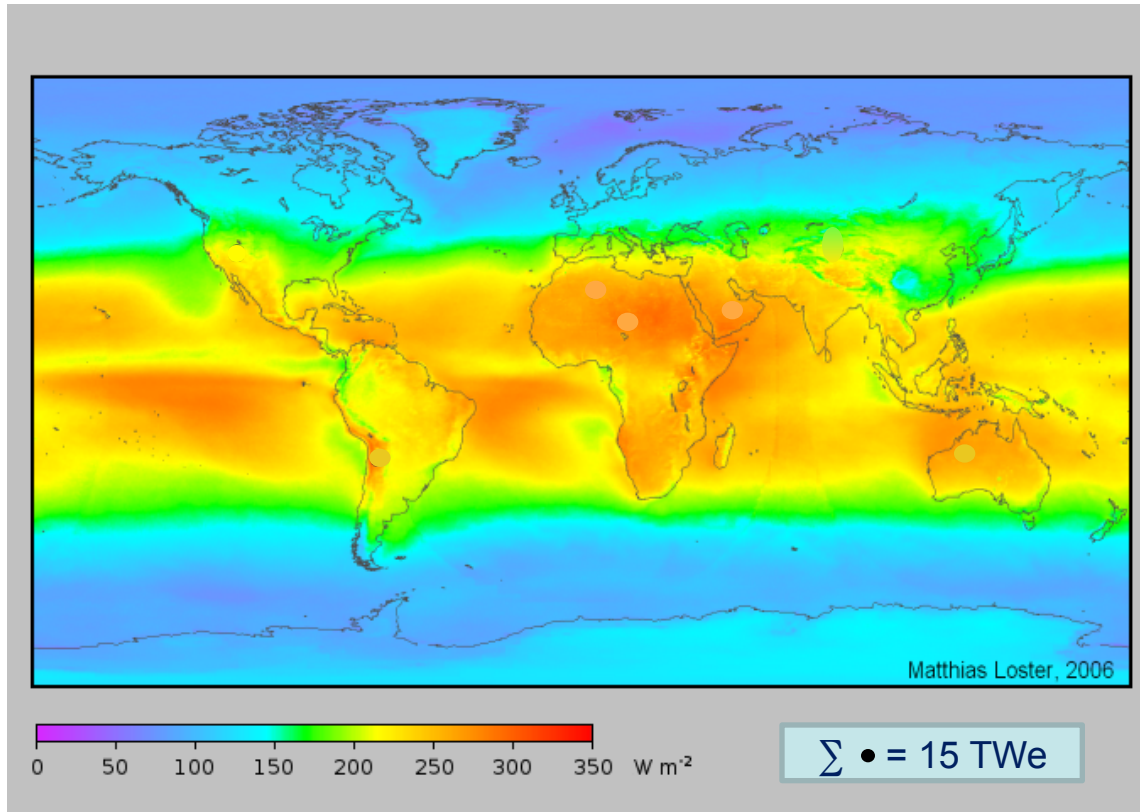
assuming 30 %
efficient solar panels

20 black dots:

area of solar
panels needed
to generate all
of the worlds
primary energy

(all energy consumed:
electricity, heat, fossil
fuels)

Solar irradiance on earth



assuming 30 %
efficient solar panels

1000 black dots:

area of solar
panels needed
to generate all
of the worlds
primary energy

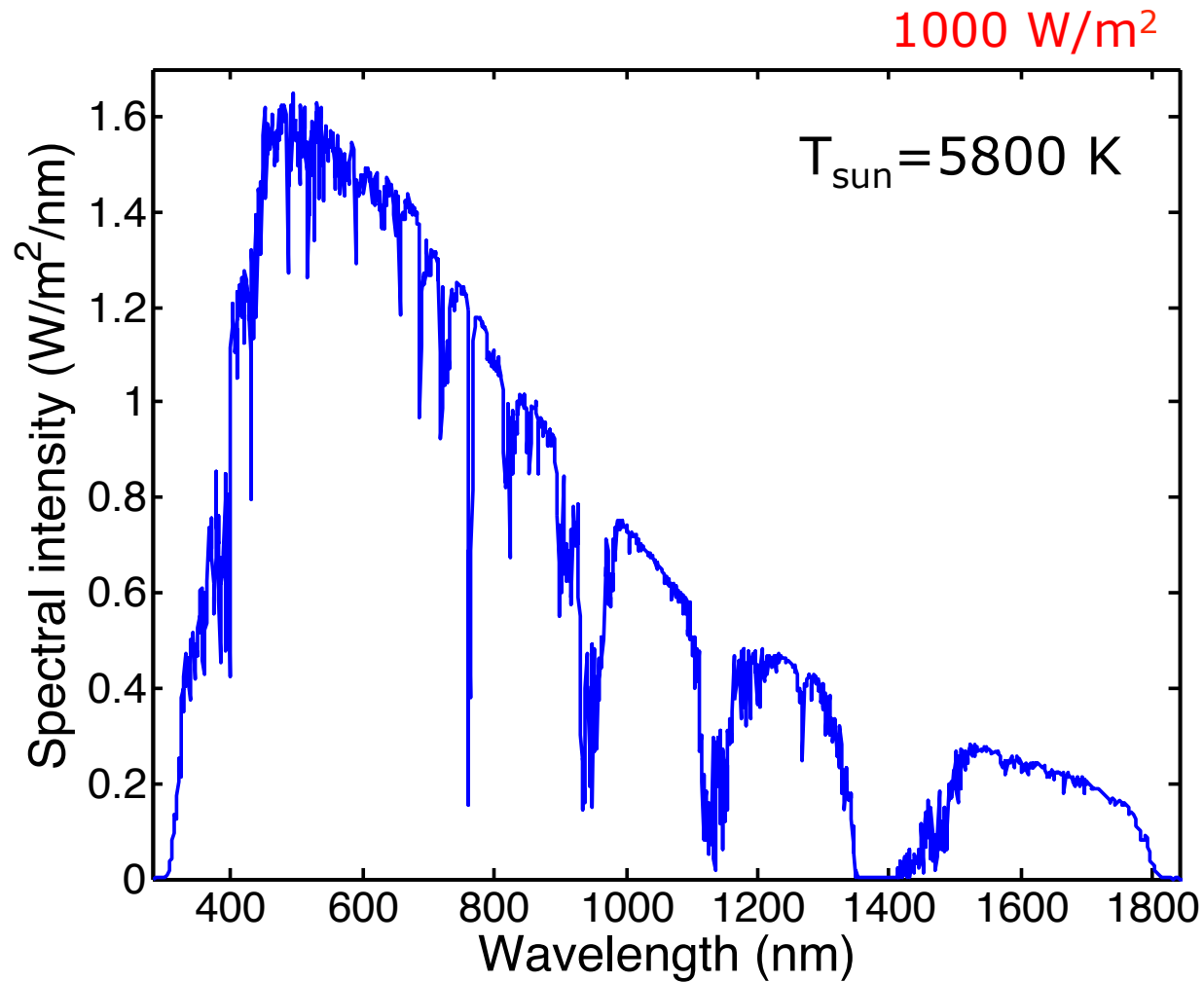
(all energy consumed:
electricity, heat, fossil
fuels)

Needed:

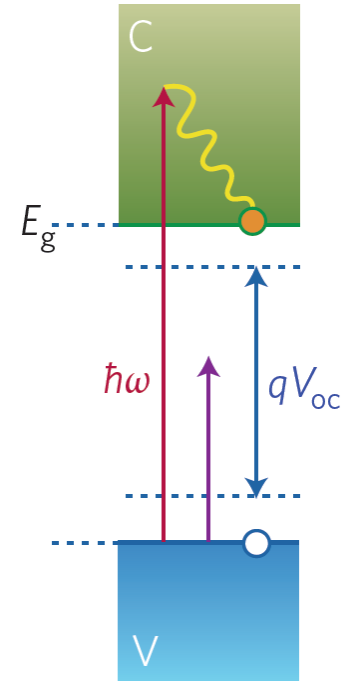
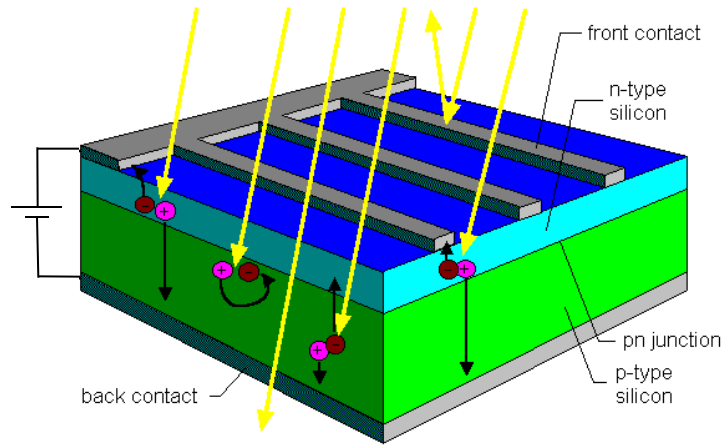
- 1) Lower costs
- 2) Higher efficiency



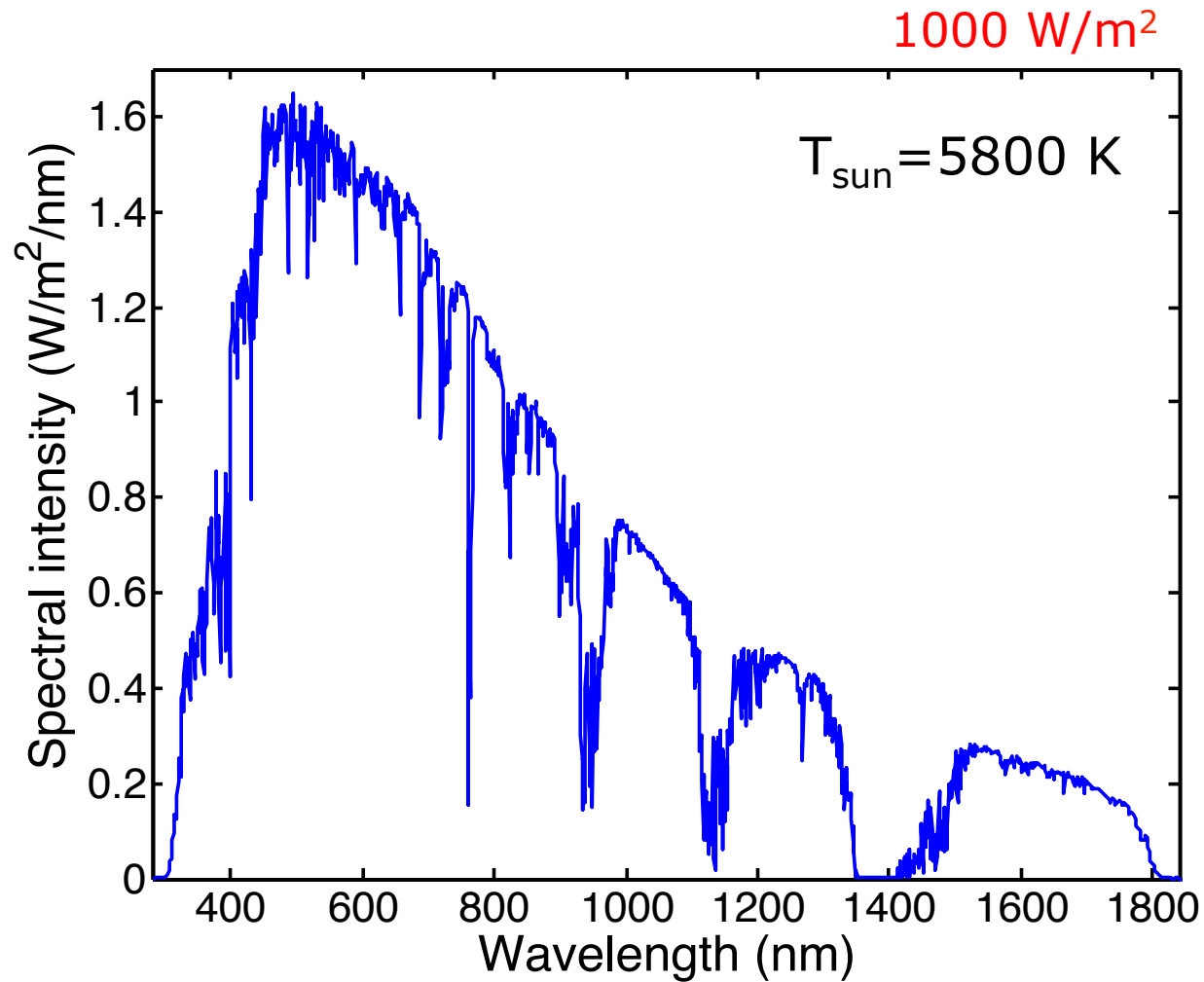
The solar spectrum



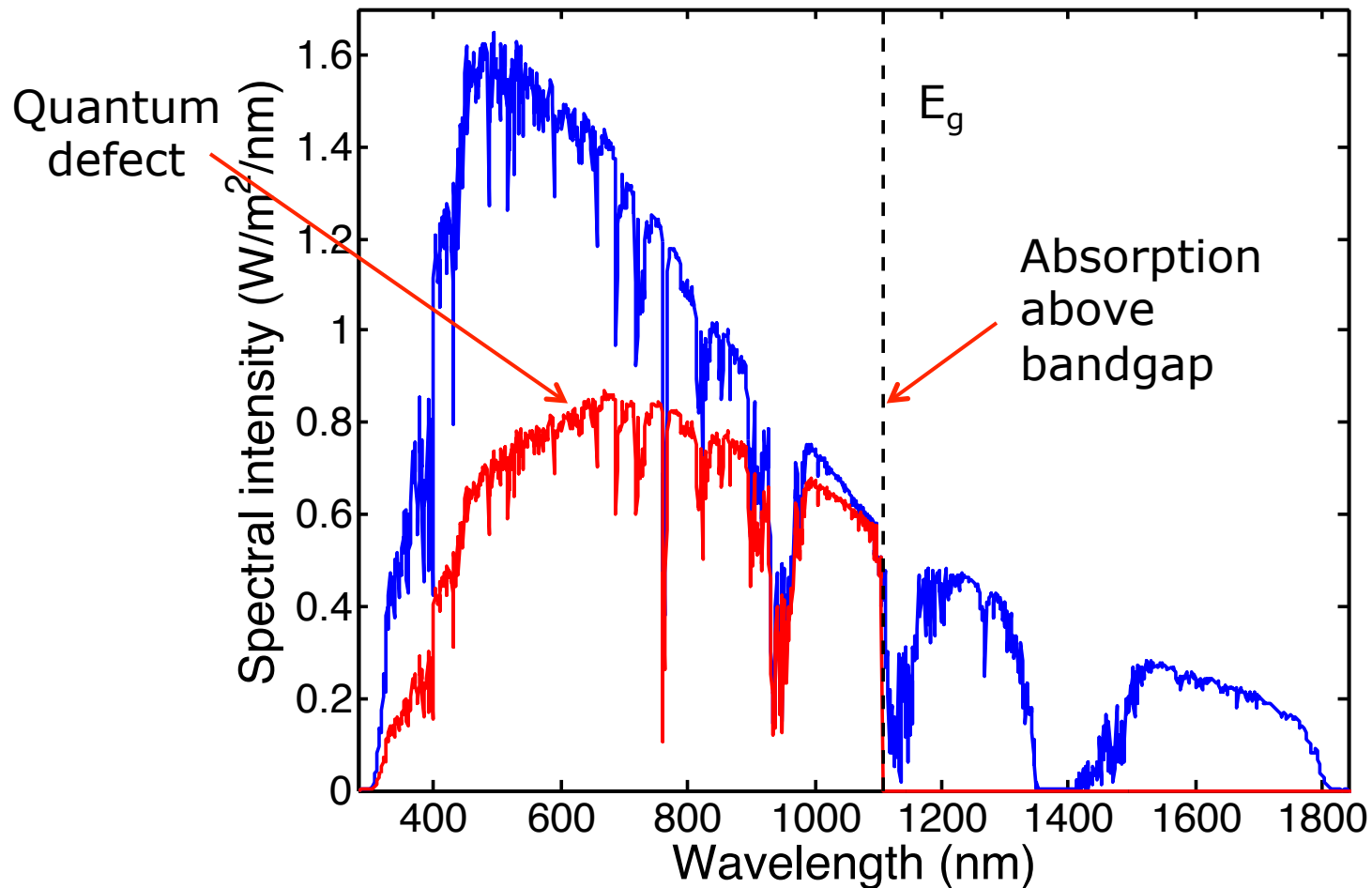
Solar cell basic design



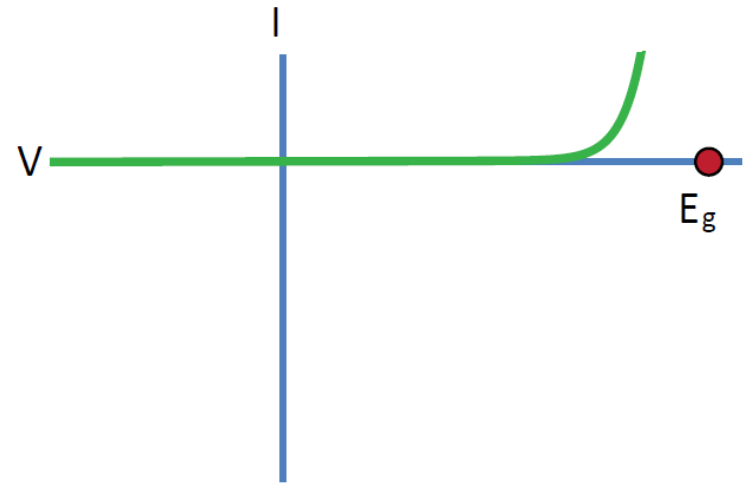
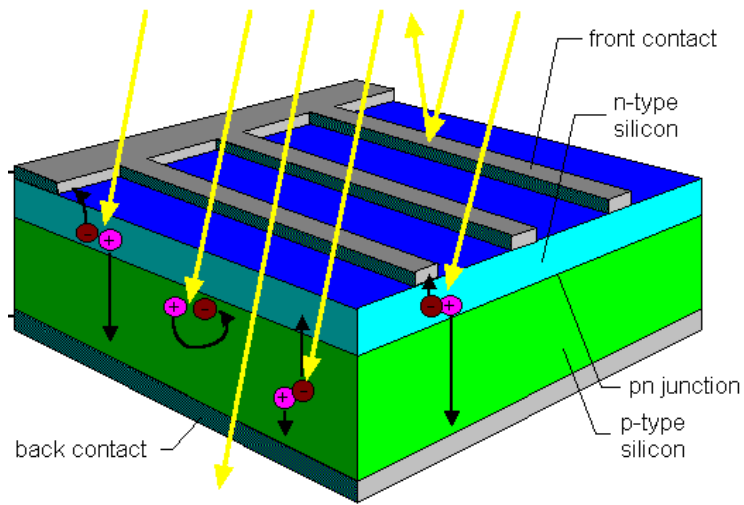
The solar spectrum



Absorption edge and quantum defect

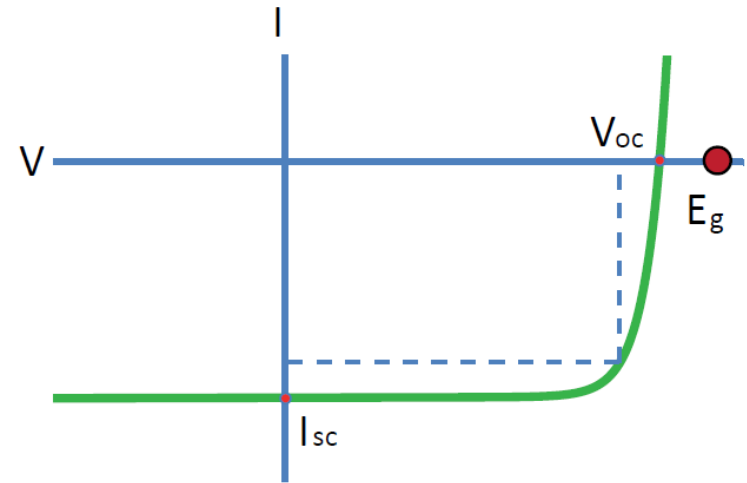
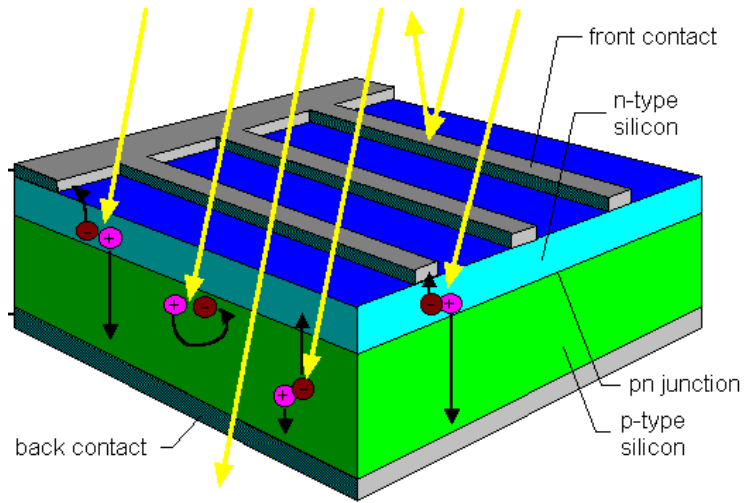


Voltage is lower than bandgap energy



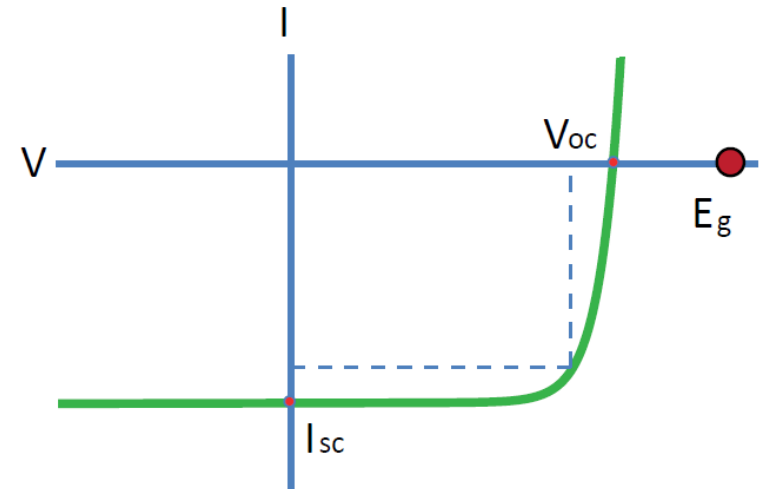
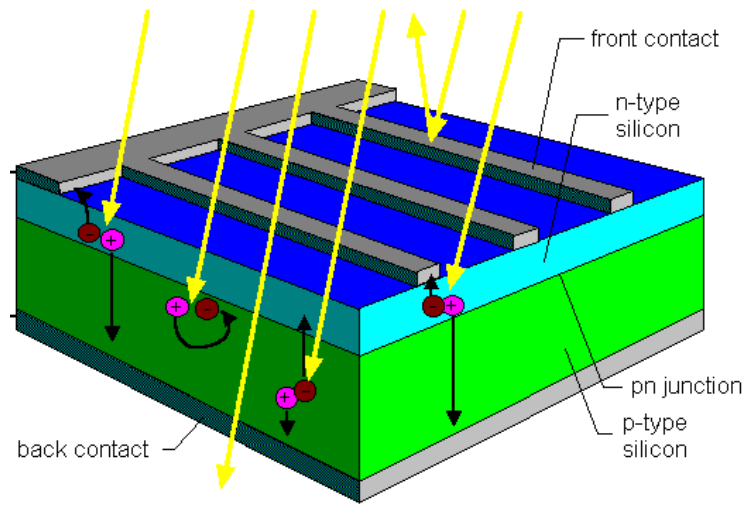
$$I_{\text{ext}} = I_0 \exp(V/kT).$$

Voltage is lower than bandgap energy



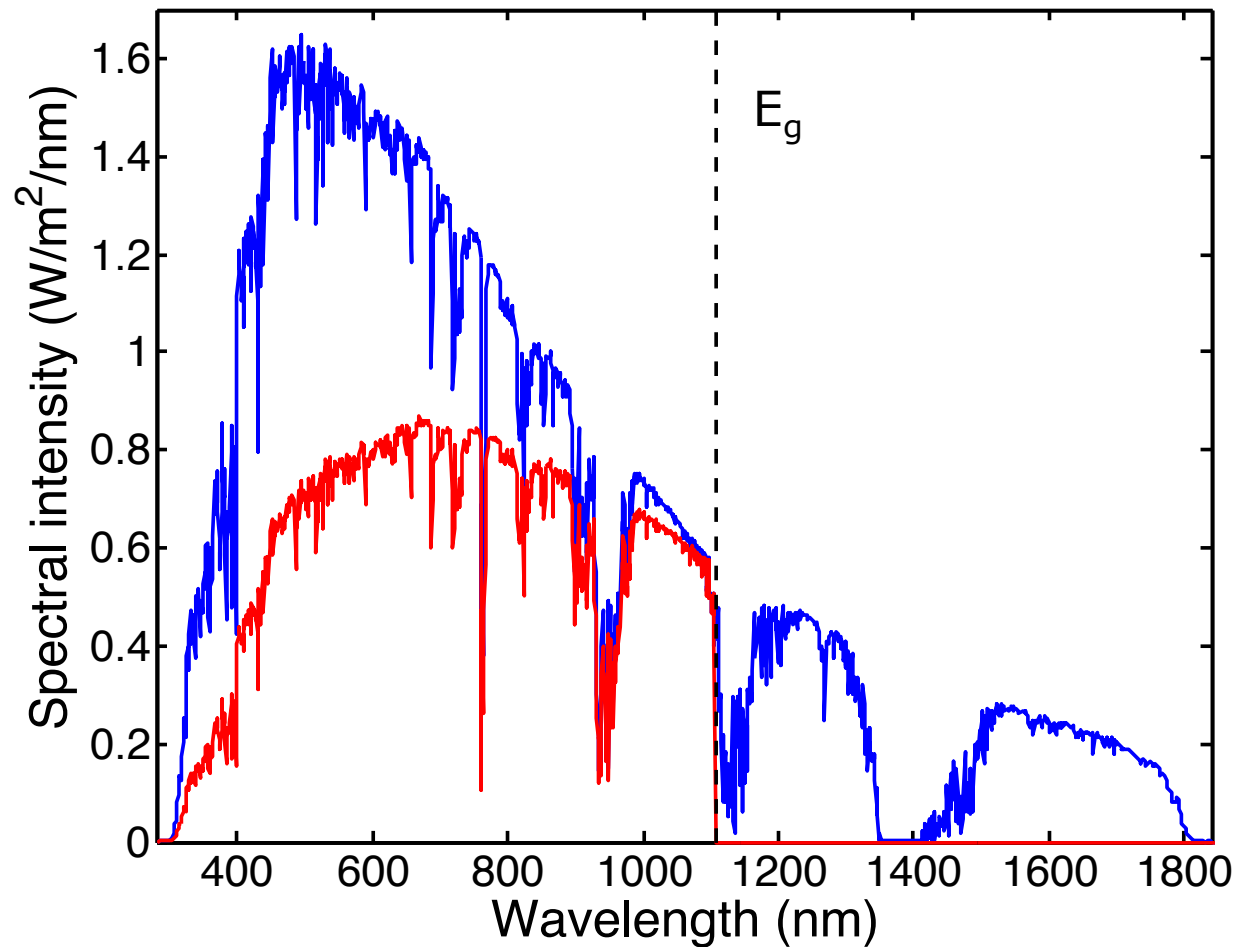
$$I_{\text{ext}} = I_0 \exp(V/kT) - I_{sc}$$

Voltage is lower than bandgap energy



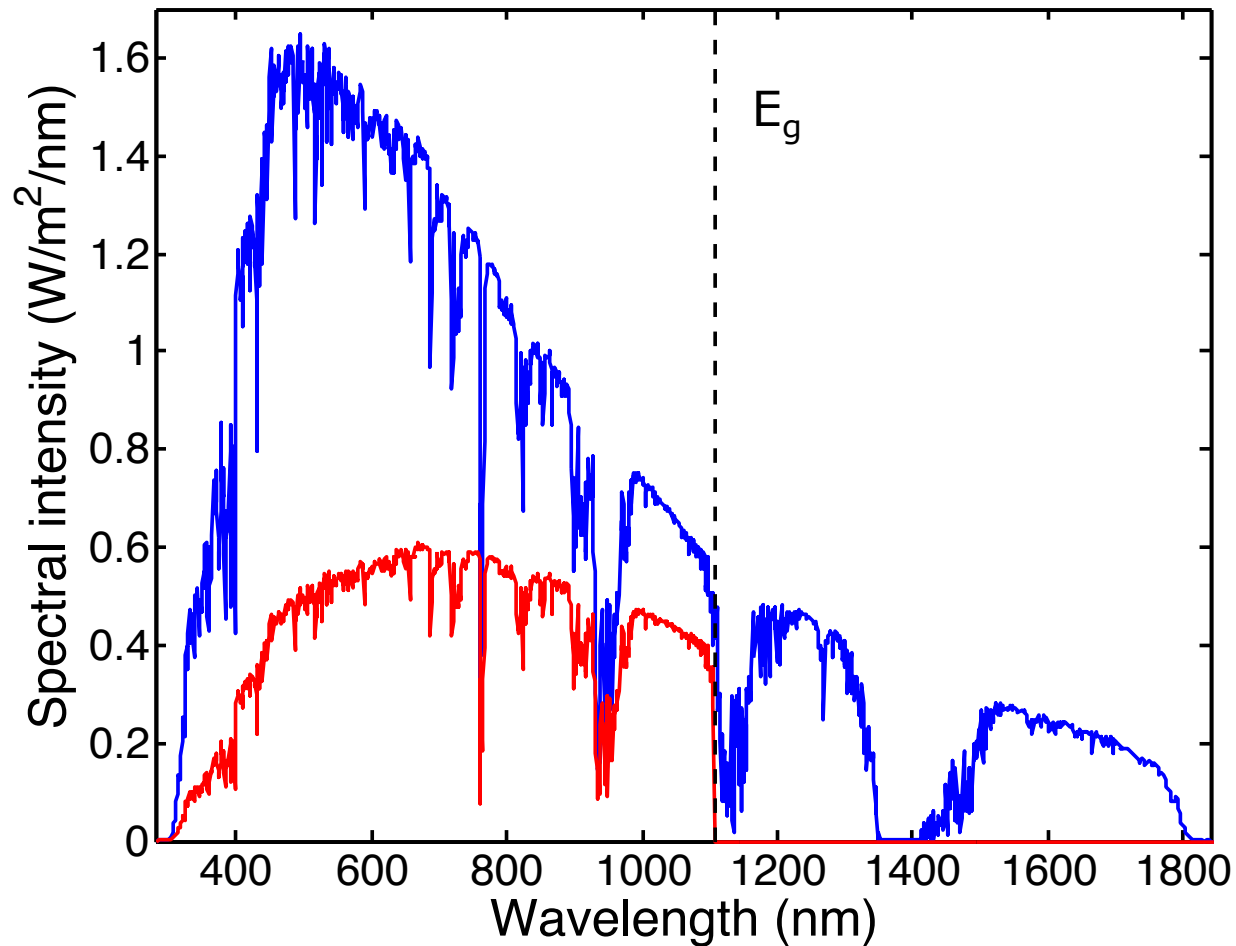
$$I_{\text{ext}} = I_0 \exp(V/kT) - I_{sc}$$

Voltage is lower than bandgap energy

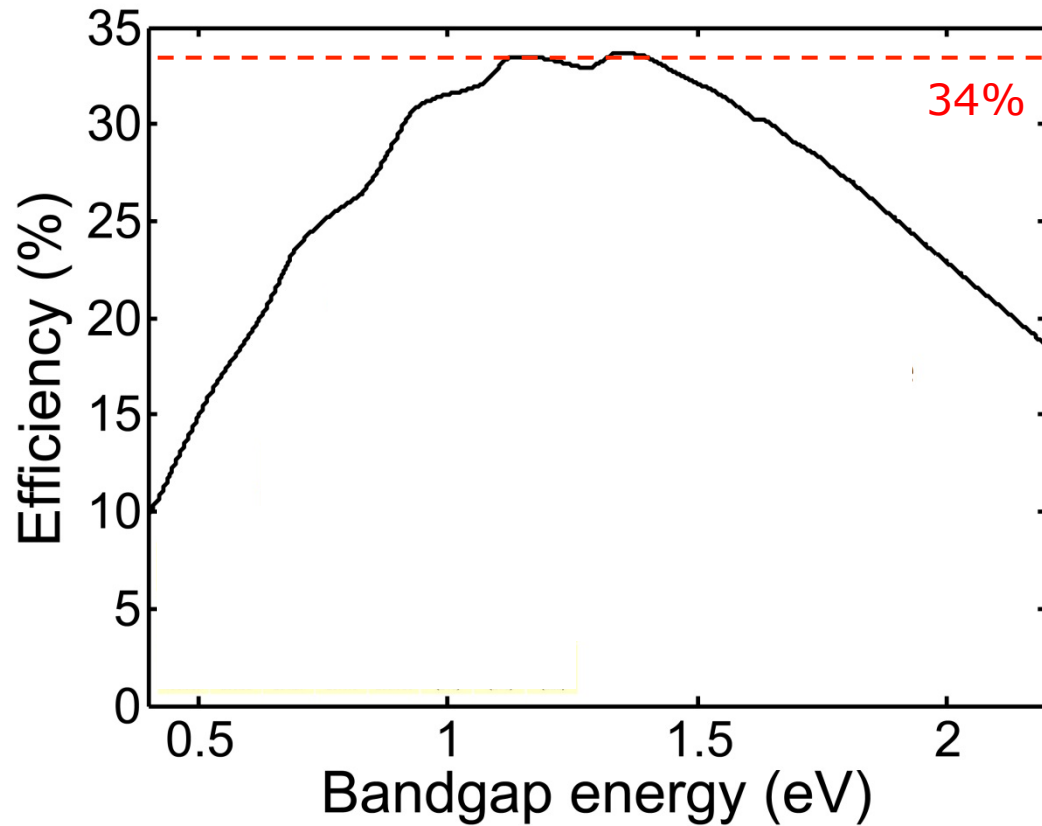


Voltage is lower than bandgap energy

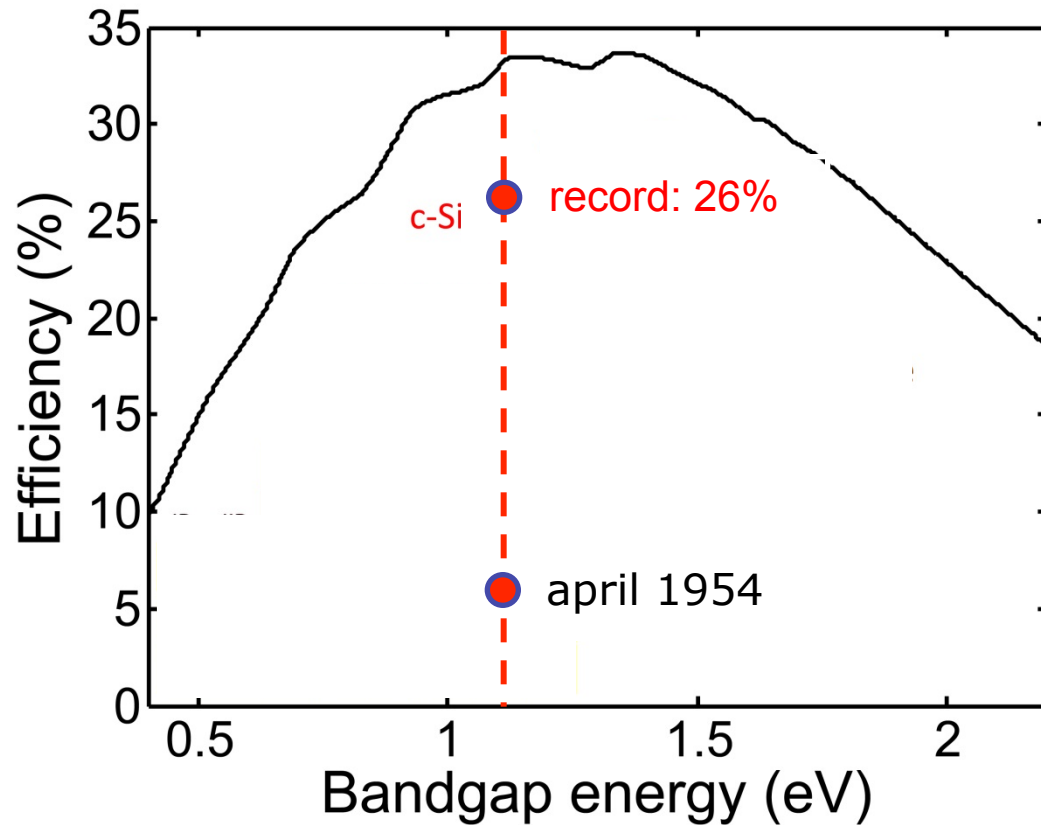
Maximum efficiency: 34%



Shockley-Queisser efficiency limit: 34%



Silicon is ideal: SQ limit = 33 %

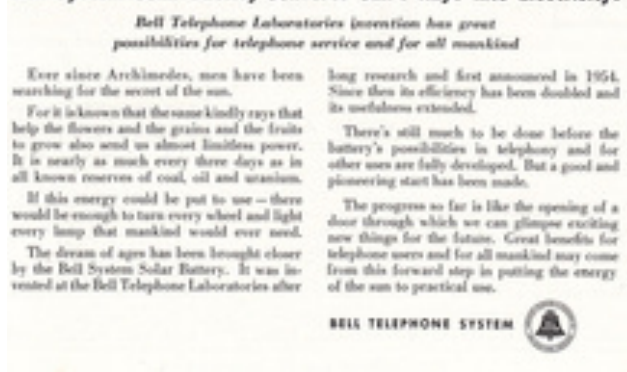


The silicon solar cell turned 60 !



April 25, 1954

New York Times: *the beginning of a new era, leading eventually to the realization of one of mankind's most cherished dreams – the harnessing of the almost limitless energy of the sun for the uses of civilization*



The first practical solar cell
Si: 6 % efficiency

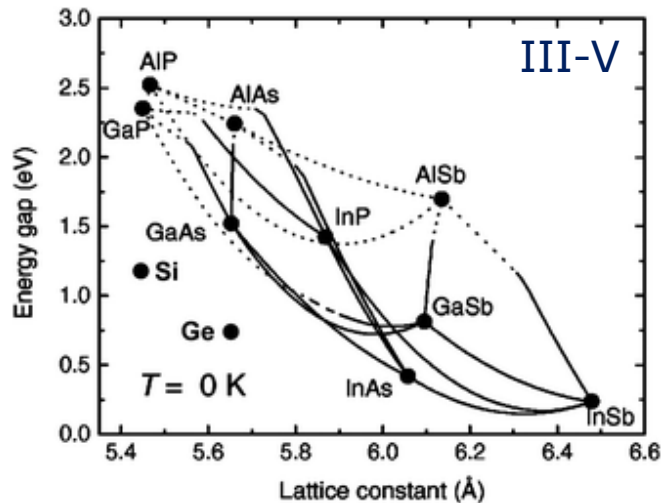
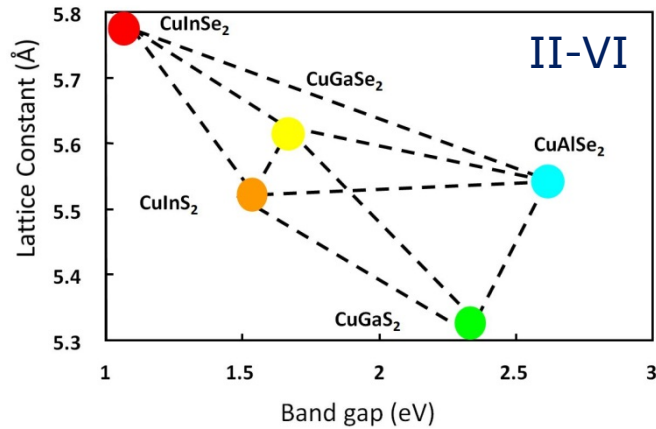
Vanguard satellite 1958



2014

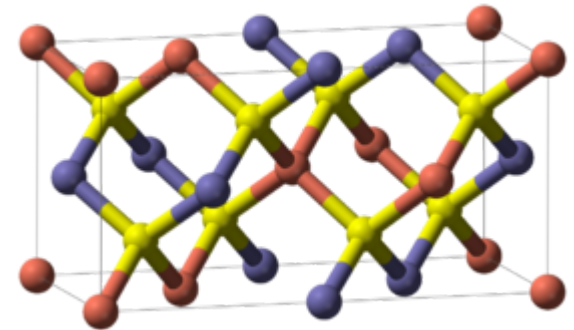
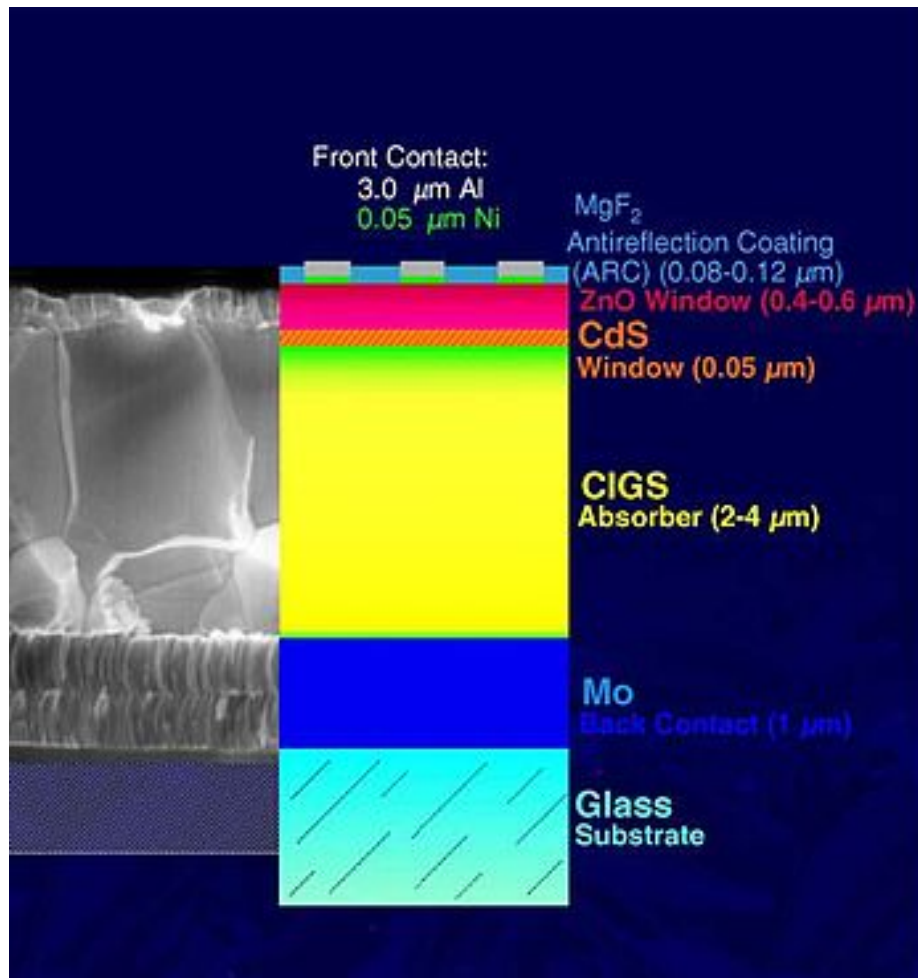


Periodic Table of solar elements

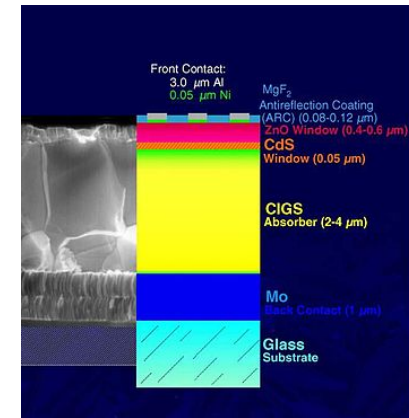
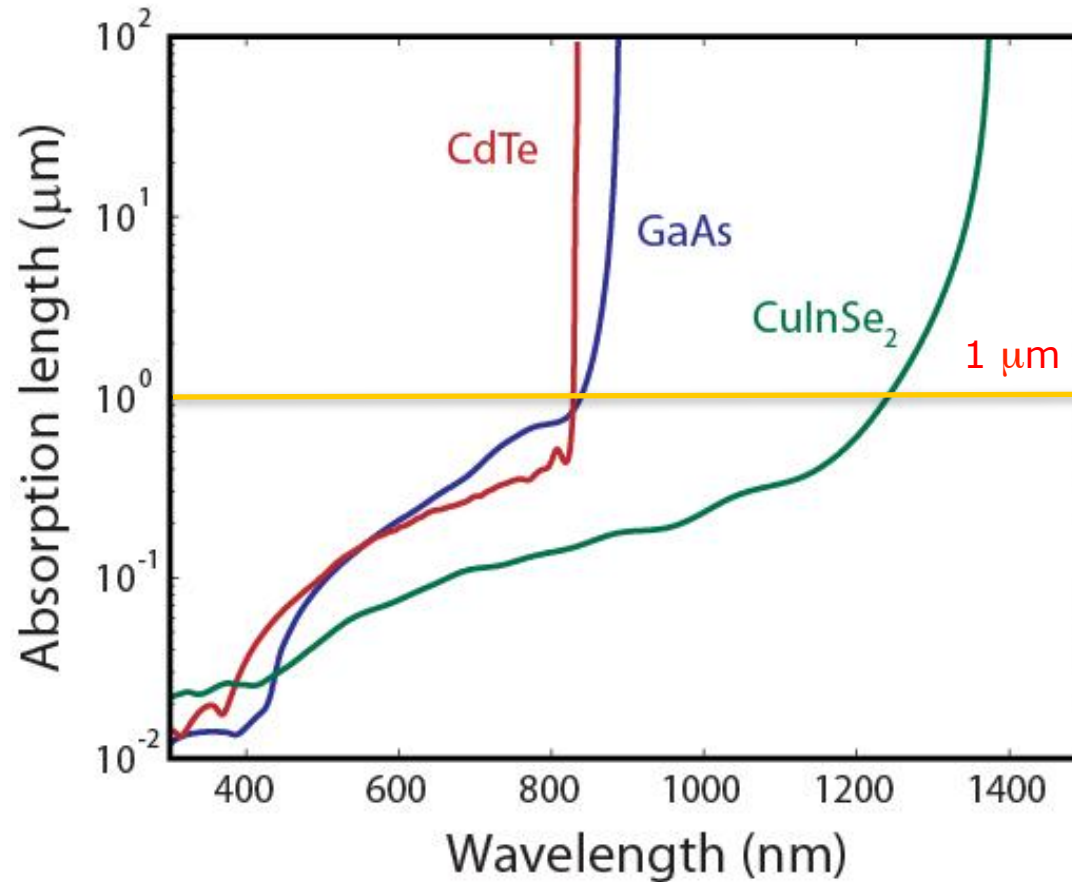
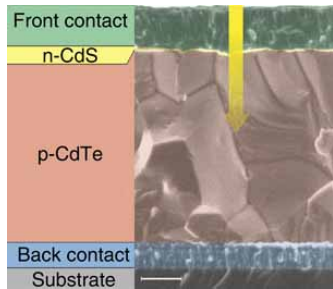


						VIIIA
						2 He 4.003
	IIIA	IVA	VA	VIA	VIIA	
	5 B 10.811	6 C 12.011	7 N 14.007	8 O 15.999	9 F 18.998	10 Ne 20.183
	13 Al 26.982	14 Si 28.086	15 P 30.974	16 S 32.064	17 Cl 35.453	18 Ar 39.948
IB	IIB					
29 Cu 63.54	30 Zn 65.37	31 Ga 69.72	32 Ge 72.59	33 As 74.922	34 Se 78.96	35 Br 79.909
47 Ag 107.870	48 Cd 112.40	49 In 114.82	50 Sn 118.69	51 Sb 121.75	52 Te 127.60	53 I 126.904
79 Au 196.967	80 Hg 200.59	81 Tl 204.37	82 Pb 207.19	83 Bi 208.980	84 Po (210)	85 At (210)
						86 Rn (222)

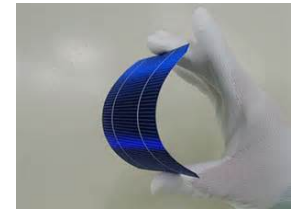
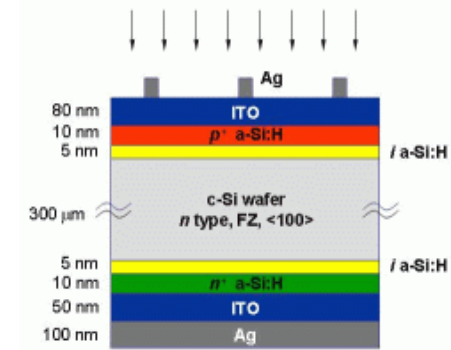
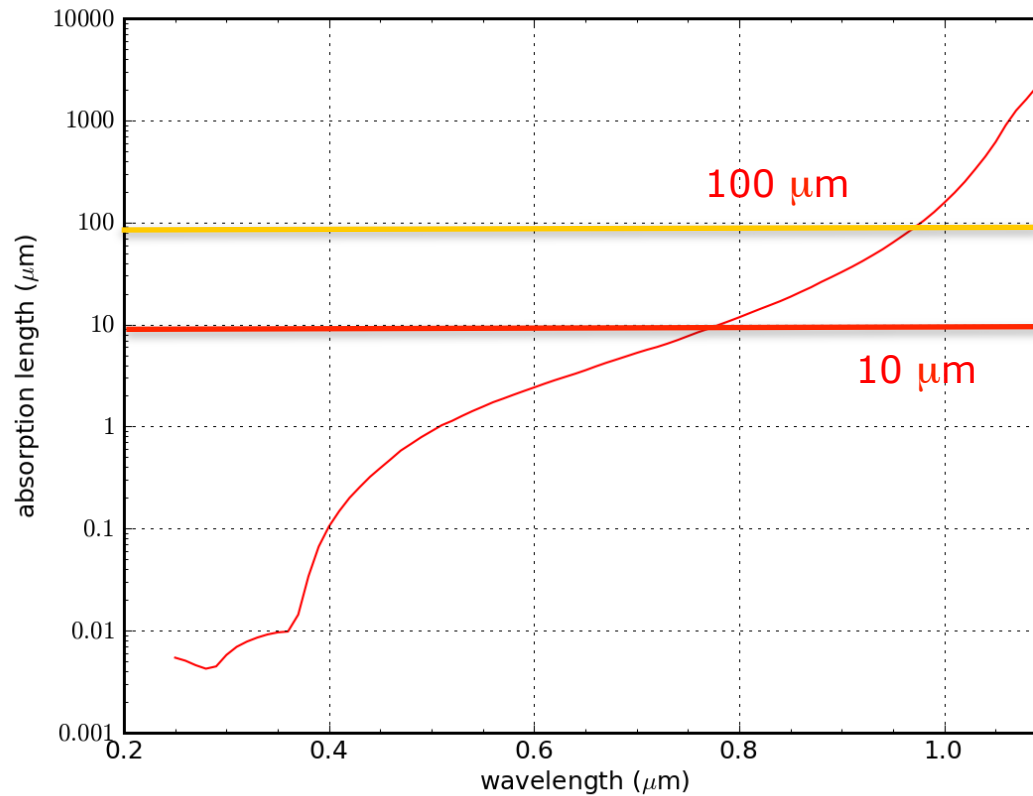
$\text{CuIn}_x\text{Ga}_{(1-x)}\text{Se}_2$ (CIGS) cells: 20.8%



Absorption length in compound semiconductors

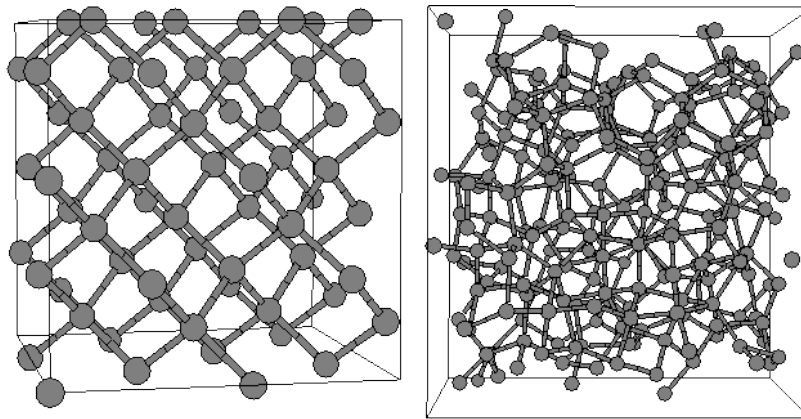


Absorption length in silicon



Si solar cell efficiencies

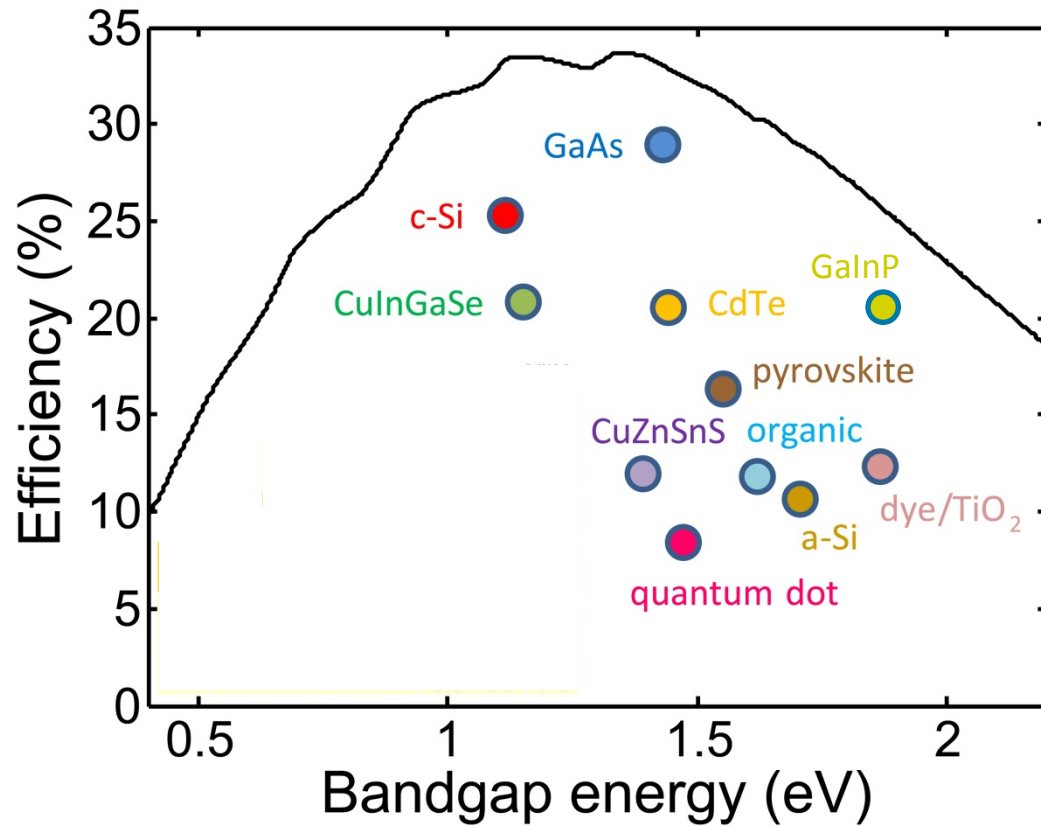
cheap expensive ↑	Material	Thickness	Efficiency	Source
	Monocrystalline Si	260 μm	25.6 %	Panasonic (Jap)
	Polycrystalline Si	99 μm	20.4 %	FhG-ISI (Ger)
	Nanocrystalline Si	2 μm	10.1 %	Kaneka (Jap)
	Amorphous Si	300 nm	10.1 %	Oerlikon (Swi)



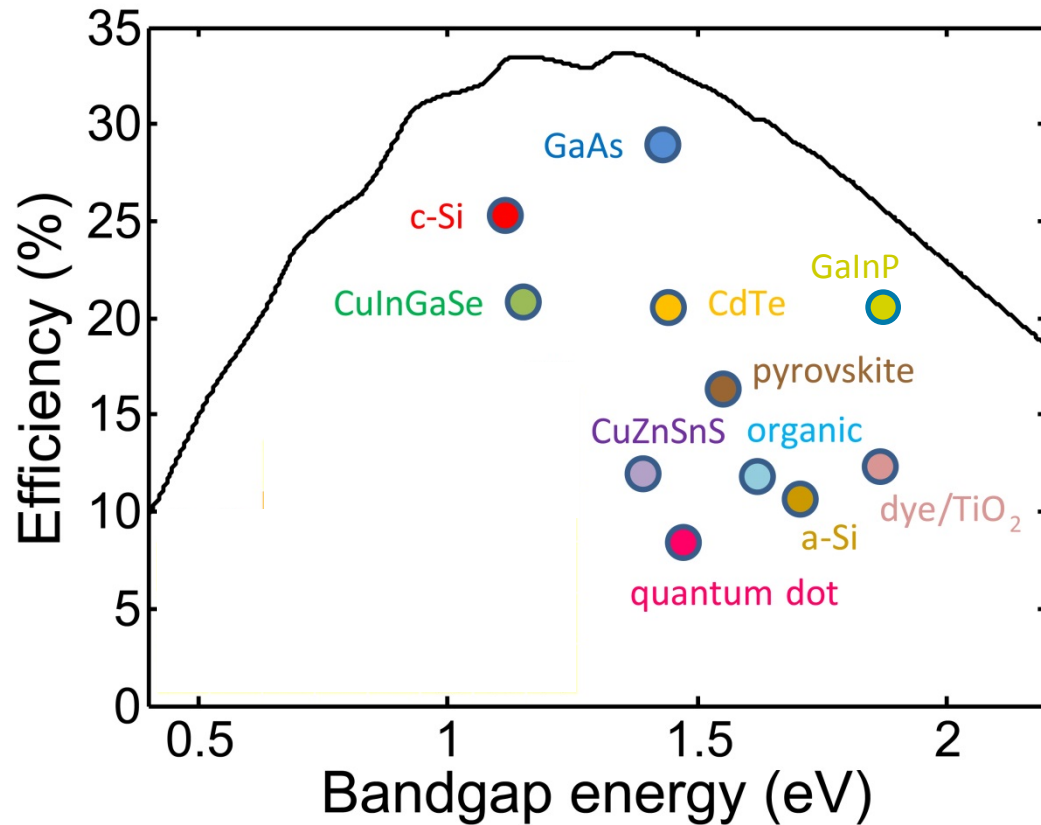
<http://www.physics.rutgers.edu/~nakhmans/Pro/thesis/node6.html>

Figure 1.1: Crystalline Si and CRN amorphous Si models. Left: 64 atom model of crystalline silicon; right: 216 atom CRN model of amorphous silicon.

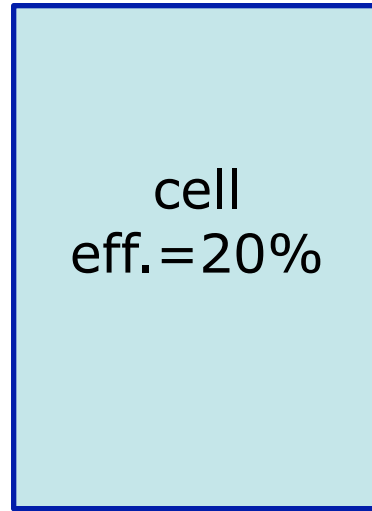
Demonstrated solar cell efficiencies



Despite 60 years of research:
No material reaches the thermodynamic limit !



Solar power generation system =
cells + panel + inverter + system + installation + land



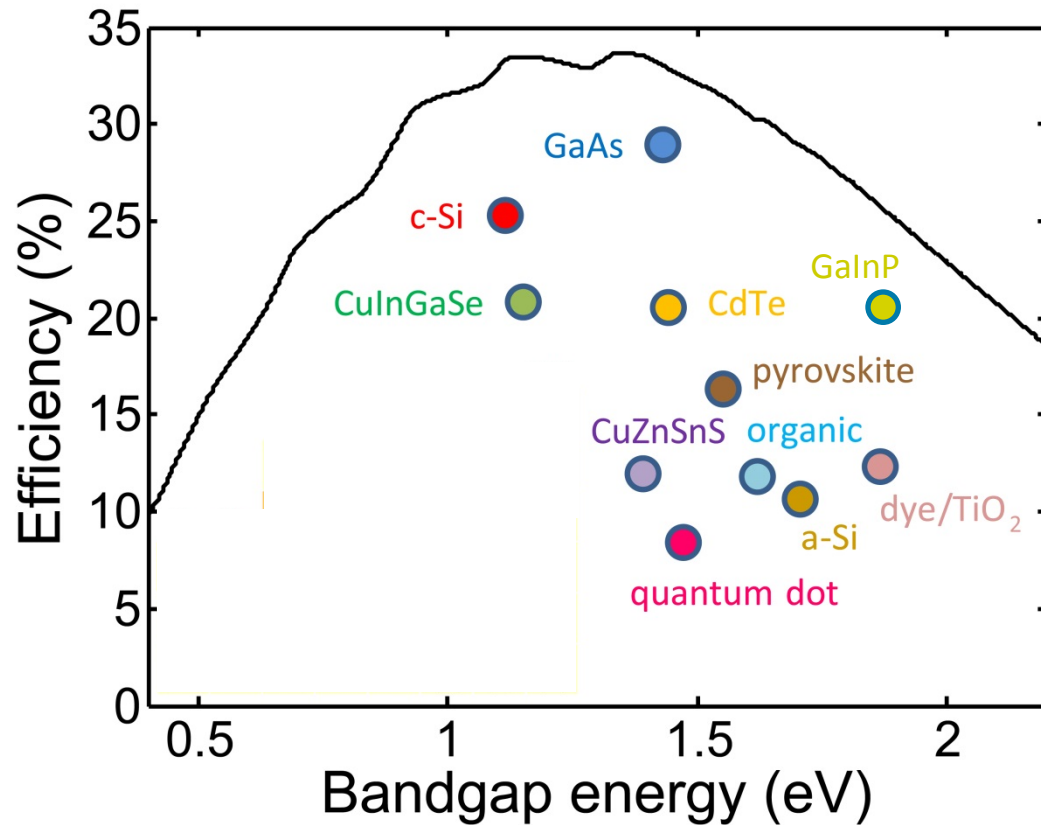
panel	€ 100
cells	€ 100
Total	€ 200

Solar power generation system =
cells + panel + inverter + system + installation + land

cell
eff.=10%

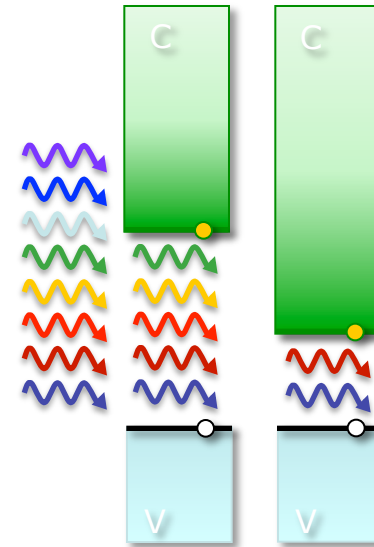
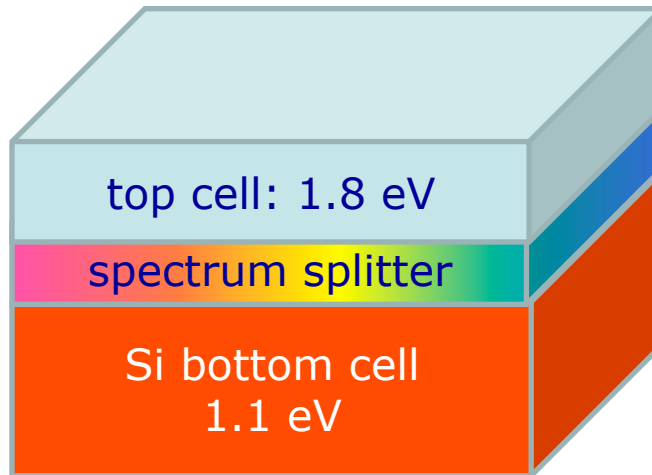
cell
eff.=10%

High efficiency is “more important” than low cost



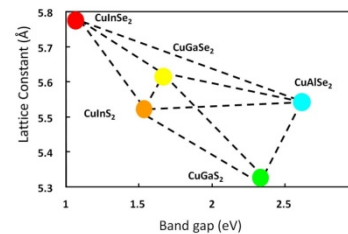
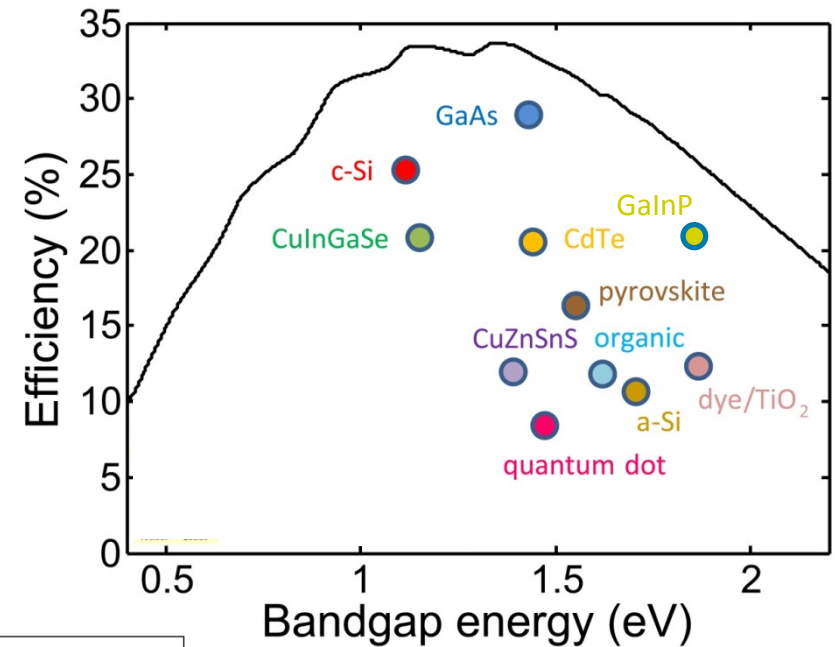
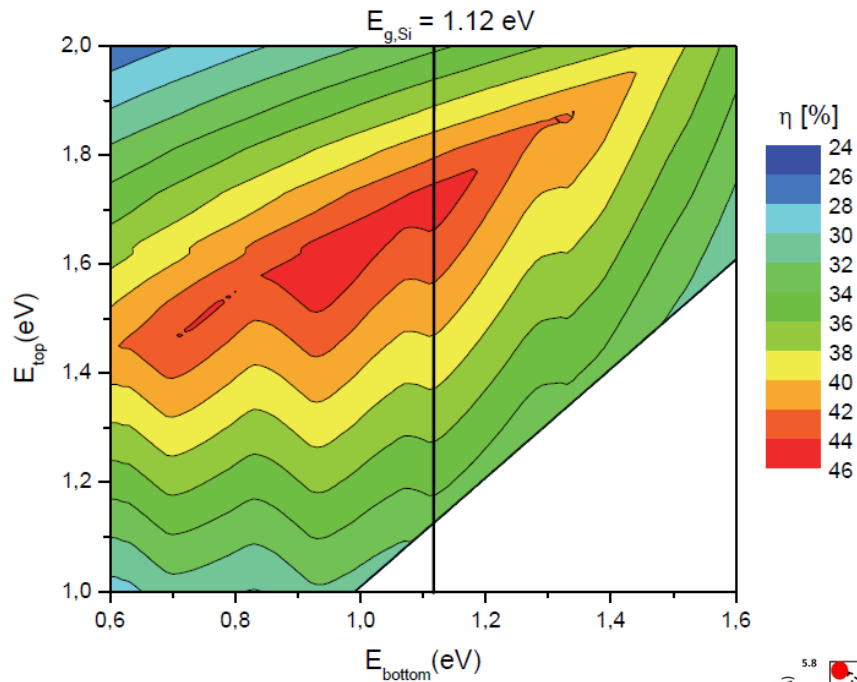
Dual-junction solar cell: thin-film-on-silicon

SQ limit: 44%

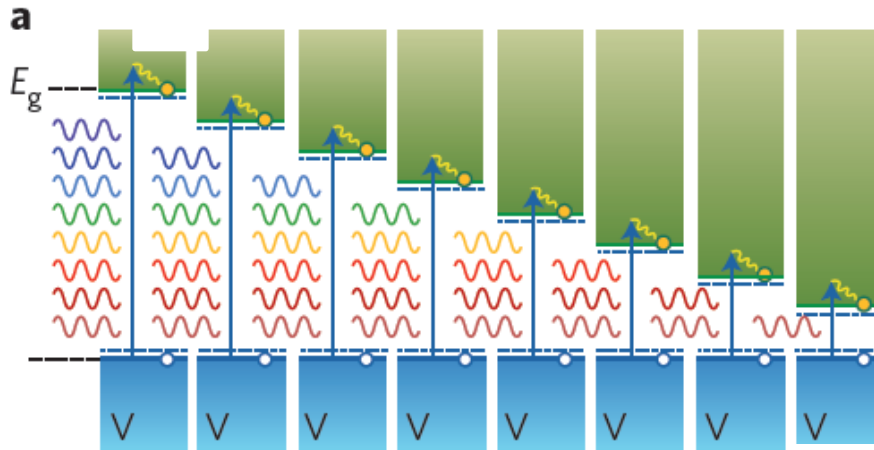


Dual-junction solar cell: thin-film-on-silicon

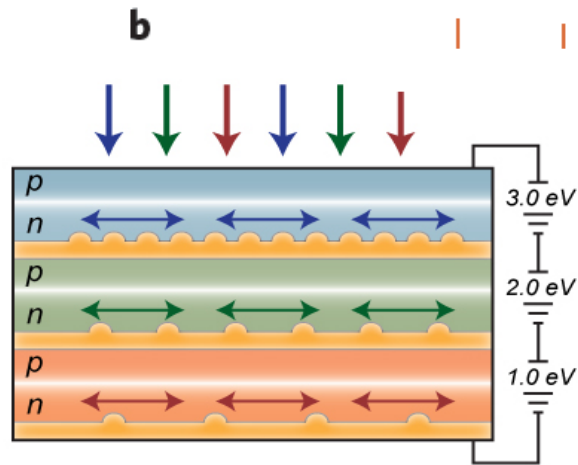
SQ limit: 44%



Multi-bandgap solar cell designs

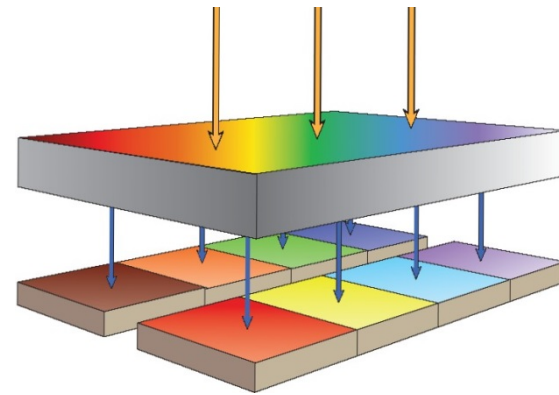


Efficiency potential
> 50%



series-connected

spectrum
splitting



parallel-connected

Strategies towards high efficiency at low costs

1) Wafer-based Si solar cells ($\rightarrow 25-29\%$)

- Reduce costs (=reduce wafer thickness: $10-20\text{ }\mu\text{m}$)
- Decrease recombination at surface, junctions, contacts
- Increase light trapping, angular emission restriction, ..

2) Thin-film solar cells

- Increase efficiency & reduce costs

3) Dual-junction solar cells on silicon ($\rightarrow 30-35\%$)

- Increase efficiency and bandgap of top cells
- Define spectral splitting architectures

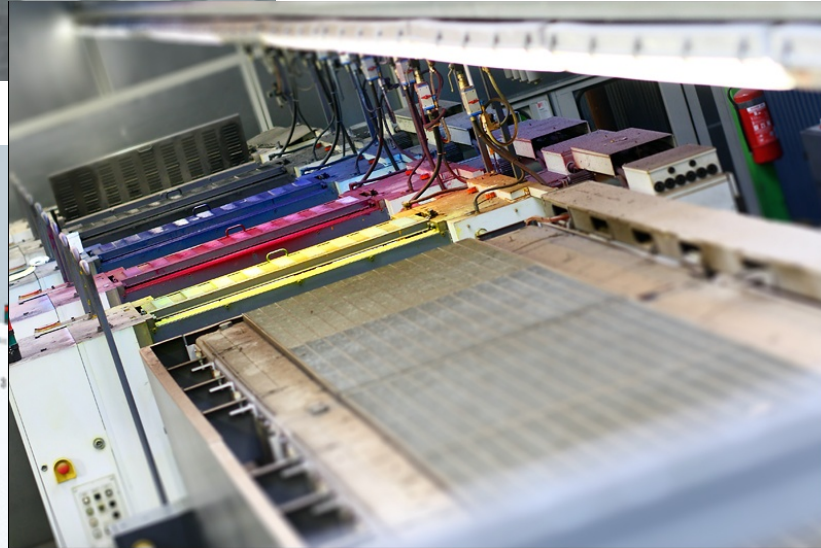
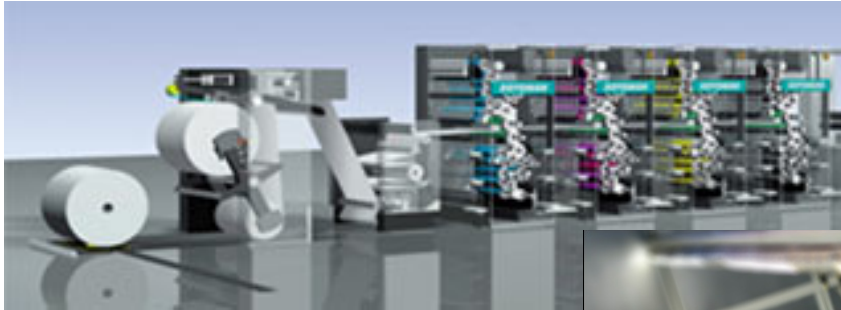
4) New materials and designs ($\rightarrow >40\%$)

- Novel multijunction cell architectures
- Nanowire solar cells
-

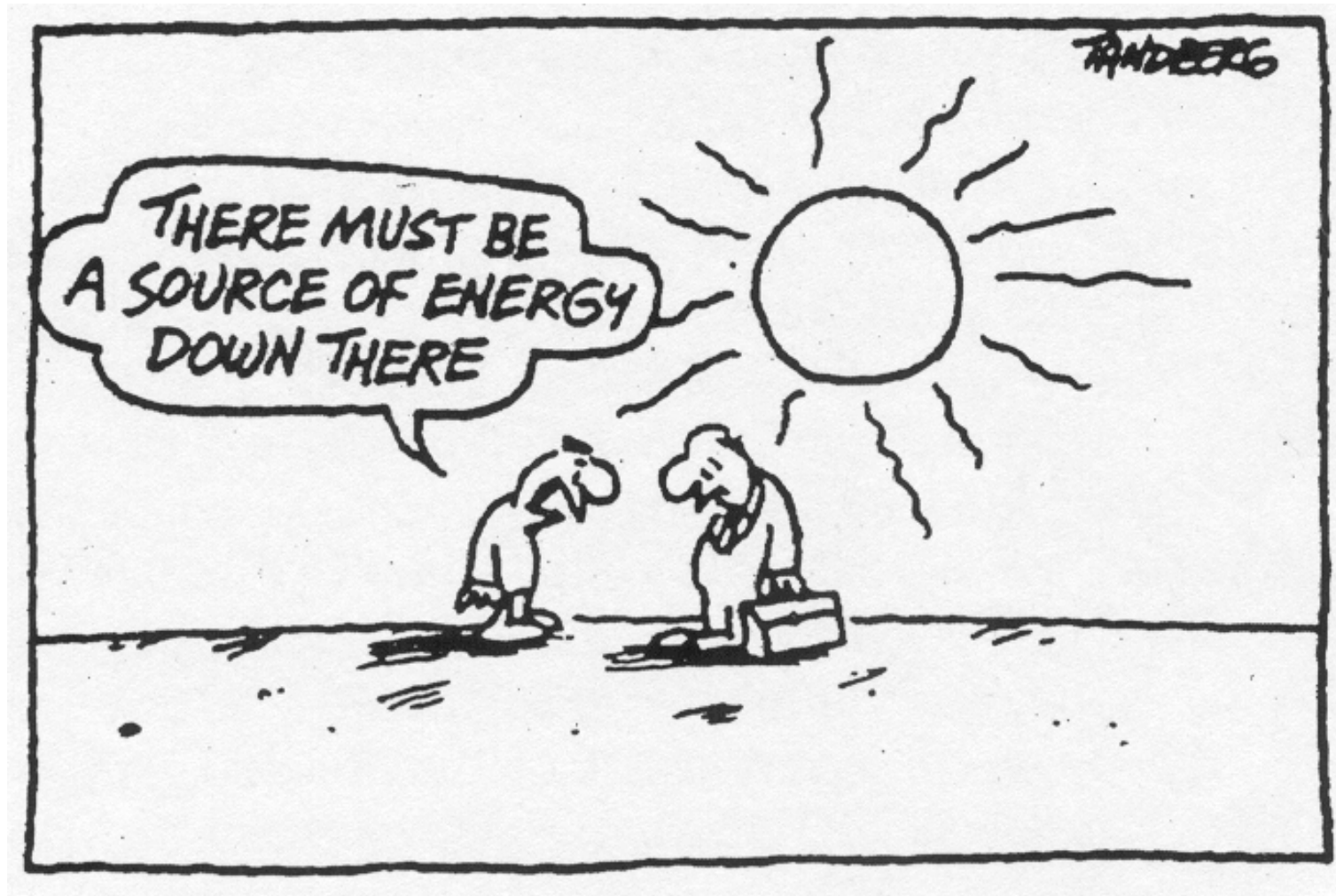
Towards ultra-large-area PV systems worldwide



Large-scale printing of solar cells



Energy from the sun



Energy from the sun

is a

science challenge
&

technology challenge
&

societal/political challenge

Thank you